# mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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## DSSK18-0025BS

preliminary

## **Schottky Diode**

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

#### Part number

DSSK18-0025BS

### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- low Irm values
- Improved thermal behaviour
- High reliability circuit operation
  Low voltage peaks for reduced
- protection circuits
- Low noise switching



#### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

# $V_{RRM} = 25 V$ $I_{FAV} = 2x 10 A$ $V_{F} = 0.37 V$



Backside: cathode

#### Package:

- Housing: TO-263 (D2Pak)
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RRM</sub>	max. repetitive reverse voltage		$T_{VJ} = 25^{\circ}C$			25	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25V	$T_{VJ} = 25^{\circ}C$			10	mA
		$V_R = 25V$	$T_{VJ} = 100^{\circ}C$			40	mA
V <sub>F</sub>	forward voltage	$I_{F} = 10 A$	$T_{VJ} = 25^{\circ}C$			0.45	V
		$I_F = 20 A$				0.56	V
		$I_F = 10A$	T <sub>vJ</sub> = 125°C			0.37	V
		$I_F = 20 A$				0.51	V
IFAV	average forward current	rectangular, d = 0.5	$T_c = 140^{\circ}C$			10	А
V <sub>F0</sub>	threshold voltage slope resistance for power loss calculation only		T <sub>vJ</sub> = 150°C			0.20	V
r <sub>F</sub>						14.6	mΩ
$R_{thJC}$	thermal resistance junction to case					1.70	K/W
T <sub>vj</sub>	virtual junction temperature			-55		150	°C
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			75	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			140	А
CJ	junction capacitance	$V_R$ = tbd V; f = 1 MHz	$T_{VJ} = 25^{\circ}C$		tbd		pF

IXYS reserves the right to change limits, conditions and dimensions.



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Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per pin <sup>1)</sup>			35	A
R <sub>thCH</sub>	thermal resistance case to heats	sink		0.25		K/W
T <sub>stg</sub>	storage temperature		-55		150	°C
Weight				2		g
F <sub>c</sub>	mounting force with clip		20		60	N

<sup>1)</sup> I<sub>RMS</sub> is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.



Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSSK18-0025BS	DSSK18-0025BS	Tape and Reel	800	499099

Similar Part	Package	Voltage class
DSB30C30PB	TO-220	30

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